# MicroNote<sup>™</sup> 132

# **AIRCRAFT LIGHTNING PROTECTION**

A Shortcut to Selecting Transient Voltage Suppressors for RTCA/DO-160 Threats

Featuring Microsemi's New

# DIRECTselect<sup>™</sup> Method

by

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# BACKGROUND

Within the thin metal and composite shell of every jetliner, tens of thousands of sensitive semiconductor components are performing critical functions from navigation to engine control. Since aircraft are struck by lightning twice a year on average, protection of sensitive electronic devices providing a myriad of functions is essential to ensuring the safety of both passengers and crew.

Although aircraft lightning threats are well defined in RTCA/DO-160, there are very few off-the-shelf transient voltage suppressors (TVSs) that are direct "plug-ins" rated for operating voltage and surge protection from the three waveforms and five levels of lightning threats defined in this document.

Lengthy calculations must often be made to convert TVS surge ratings at standard 10/1000 µs to their equivalent values for specified aircraft lightning threats. In addition, matching a device with the threat can be cumbersome. Our MicroNotes 126, 127 and 130 illustrate these computations, providing a path from defined aircraft surge requirements to the parameters of available TVS products suitable for a given application. With those many resources, there is also **Now a better way using Microsemi's** *DIRECTselect*<sup>™</sup> to quickly guide the designer to a suitable solution **including considerations for elevated temperature deratings where applicable**.

#### DIRECTselect Method

Here is how it works: Define your surge requirements as specified in DO-160F in Section 22, Induced Transient Susceptibility per waveform, 3, 4, or 5A and Threat Levels 1 through 5 as specified in Table 22-2. Herein are the threat levels for Pin Injection that define the most severe threats to your circuit. Most requirements combine Waveforms 3 and 4. Since Waveform 4 ( $6.4/69 \ \mu$ s) is more severe, by a factor of 3.8 [1], we have included only Waveform 4 on our charts for simplicity. Values of Waveform 3 only, when required, are easily calculated using the guidance in MicroNote 127 [2].

For reference, Waveforms 3, 4, and 5A are illustrated in Figures 1, 2 and 3 respectively



	Waveforms								
LEVEL	3	4	5A						
	Voc/Isc	Voc/Isc	Voc/Isc						
1	100/4	50/10	50/50						
2	250/10	125/25	125/125						
3	600/24	300/60	300/300						
4	1500/60	750/150	750/750						
5	3200/128	1600/320	1600/1600						

Figure 4. Matrix of Threat Levels 1 through 5 from Table 22-2 in RTCA/DO-160.



This table defines the peak open circuit voltage (Voc) and peak short circuit current (Isc) for each of the waveforms listed. In making your TVS selection, maximum **Working Standoff Voltage (V**<sub>WM</sub>) values are required along with the **Peak Pulse Current (I**<sub>P</sub>) threat, where the **graphs shown on pages 14 thru 31** are plotted with I<sub>P</sub> vertically and V<sub>WM</sub> horizontally. The I<sub>P</sub> as displayed on the graph must exceed the curve depicting the current limit of the Threat Level. Examples will lead you through the selection process.

Individual graphs exist for each TVS product family and are arranged in ascending order of power rating and surge current from 500 W up through 30,000 W. These graphs are also a further extension of information in Tables 1 and 2 of MicroNote 130 [3] with added consideration for 70°C and 100°C. Graphs 1 through 9 are associated with Waveform 4 and Graphs 10 through 18 are associated with Waveform 5A. Each graph is accompanied by a supplemental table containing multiple data points from which each curve was derived, plus a list of the applicable Microsemi products for use with these specific surge current threat levels. This presentation provides direction for TVS selection for a broad distribution, from low voltage, low level lightning threats on data lines up through high levels for power distribution lines.

# ABNORMAL VOLTAGE CHARACTERISTICS

Other critical voltage parameters for selecting TVS products may sometimes include extended **Surge Limits** associated with abnormal voltage. These are maximum excursions above the nominal operating voltage. Surges differ from transient voltage in that they are long term **Abnormal Voltage Characteristics** with high-line voltages extending for durations of tens, up to hundreds of **milliseconds that can destroy TVSs**.

These voltage anomalies are caused by normal generator functions and must be considered in TVS selection. An example of the **ac abnormal voltage surge curve**, displaying voltage vs time is shown in **Figure 16-5 of the RTCA/DO-160**, **Section 16 specification** as illustrated below in Figure 5:



#### Figure 5. Envelope of AC Abnormal Voltage Surges from Figure 16-5 in RTCA/DO-160

The normal operating voltage values in this graph are for 115 V rms. The rms values must be converted to peak ac values for comparing TVS parameters since the TVSs are characterized for peak, not rms values. **A TVS will not withstand the long surge durations of abnormal voltage surge**. They must be selected so that the maximum Peak Working Voltage,  $V_{WM}$ , is equal to or greater than the peak abnormal voltage. Higher magnitude short transients well beyond these voltages such as found in Waveform 3, 4 and 5A are still clamped after exceeding the V<sub>BR</sub> of the properly selected TVS. For 230 V rms lines, double the values shown in the graph above [4].



DC power lines are also plagued with the same anomaly, **abnormal dc voltage surge**, resulting from voltage excursions produced by the generators. For dc power, there are three categories of surge voltage as shown in RTCA/DO-160, Section 16, Figure 16-6 as also shown below in Figure 6.



Figure 6. Typical Abnormal DC Voltage Surges per Figure 16-6 in RTCA/DO-160.

Note that there are **3 categories of abnormal voltages** for 28 V nominal and **with 100 ms worst case surge**, similar to the ac power lines. Three levels of abnormal voltages are listed; **Category A, B and Z** with the most common requirement being **Category B**. For 14 V dc requirements, divide these upper voltage limits by 2 for the applicable values [5].

As with the envelope for the ac voltages, the  $V_{WM}$  of the TVS must be equal to or greater than the abnormal voltage limit. For exceptions, consult factory.

# **DEFINITIONS FOR GRAPHS 1 THROUGH 18**

The green, blue and yellow curves represent the ratings of the TVS device in terms of rated Peak Pulse Current ( $I_P$ ) at ambient temperatures. The  $I_P$  is shown in the vertical axis and Working Voltage ( $V_{WM}$ ) in the horizontal axis. The **green curve** on each graph depicts the peak surge current rating versus working voltage at **25°C** along with additional curves for derating to **70°C** (blue curve) and **100°C** (yellow curve). The red Curves, represent the **Pin Injection current threat levels** as defined by the **RTCA/DO-160 specification** and are labeled accordingly. If the curve for the applicable ambient operating temperature is above the red curve designating the maximum threat level, the TVS device will perform at that threat level. Only those levels that are applicable for the associated device families are included on the graph.

The eighteen individual graphs in this document cover the entire DO-160 threat range. Nine of these graphs display surge threats and surge capability of the TVSs for Waveform 4 (6.4/69  $\mu$ s) and nine display this same information for the more severe Waveform 5A (40/120  $\mu$ s). Values shown on the graph include the +20% high side tolerance of the pulse widths.

Based on requests from the aerospace industry, Microsemi devices meet the vast majority of needs. If no part exists for a given voltage and surge current rating, custom components can be designed. Consult the factory for these options.

#### **GRAPH OVERVIEW**

Each graph is derived from the peak pulse current ( $I_{PP}$ ) levels at 10/1000 µs ratings of the product data sheet. For the shorter aircraft transients, the power levels are higher, by a factor of 3.33x for the 6.4/69 µs waveform and 2.33x for the 40/120 µs waveform and are labeled as  $I_P$ . These multiplication factors include the +20% tolerance of the threat duration [6]. For Waveform 4, the graph numbers and associated TVS power levels with part types are listed on the following page. Except for 1Nxxxx part numbers shown that already have military qualifications, add M prefix for source control or MA, MX, or MXL for further upgrade screening options on plastic devices as described in MicroNote 129.



Graph Number	TVS Power Level @ 10/1000 μs	Product Series (more details on graphs)
1	500 W	1N6103A-1N6137A, 1N6461-1N6468, 1N8073-1N8109, P5KE, SMBJSAC
2	600 W	P6KE, SMB
3	1500 W	1N5629A-1N5665A, 1N5907, 1N5908, 1N6036A-1N6072A, 1N6138A-1N6173/ 1N6469-1N6476, 1N8110-1N8146, 1.5KE, SMC, SMCJLCE
4	3000 W	SML
5	5000 W	5KP
6	6500 W	PLAD6.5KP
7 8 9	7500 W 15,000 W 30,000 W	PLAD7.5KP 15KP, PLAD15KP PLAD30KP

A more complete listing of each product series is shown on its associated graph. NOTE: A **second series of graphs (10 through 18)** are also included for **Waveform 5A** and contains equivalent information on the product series as waveform 4 above with **threat levels** increased to the magnitude of waveform 5A.

#### USING DIRECTselect - EXAMPLES FOR WAVEFORM 4

For our **first example**, let's consider a low level transient voltage threat to an **ARINC - 429, +/- 5 V** data line. For this illustration, the **lightning threat** requires protection from **Waveform 4, (6.9/69 µs) Level 3** (300Voc/60lsc). Applications with voltages going in both positive and negative directions require bidirectional TVS devices.

We know the selection will be within the **first few** of the **seven graphs** because of the relatively low current rating requirement. Since the **lowest voltage** devices have the **highest current ratings**, the device would most likely be found on the first one or two graphs.

In reviewing **Graph 1**, **the 500 W TVS at 5 V working voltage (V**<sub>WM</sub>) **has a peak current rating of 180 A.** This is well above the necessary **requirement of 60A** for **Level 3** with margin for **temperature derating up to 100<sup>o</sup>C.** In the supplementary table, data points for these graphs are provided that include the major parameters: Peak Pulse Current (I<sub>PP</sub>), Clamping Voltage (V<sub>C</sub>), and V<sub>WM</sub>. Exact values not shown can be extrapolated from this data.

Device selection for the **ARINC - 429**, **Slow Data rate** signals, **10-11** kHz, would be the SMBJ5.0C or **SMBJ5.0CA**. For the **Fast Data** rate signals at **100** kHz, the selection would be the **SMBJSAC5.0** with low capacitance of **30** pf or less. Two of these devices are required in anti-parallel to achieve bidirectional protection. Refer to the data sheet on Microsemi's web site for complete information on installing this part. The selection shown is a surface mount device; however these parts are also available in axial-leaded configurations.

In our second example, a TVS is required for performance to Waveform 4 ( $6.4/69 \mu$ s), Level 3 (Voc300V/Isc60A) for +/-48V ac. This application also requires a bidirectional device and must have a higher power rating than in the previous example because its operating voltage is significantly greater. Since silicon TVSs provide the same power rating within a series ( $P_{PP} = I_{PP} \times V_C$ ), the current rating will be about one-tenth of the value for a 48 V TVS compared to a 5.0 V device in the same series. However, the peak pulse power requirement is greater for this application, so we continue our search among the graphs for a higher power device. In Graph 3, for the 1500 W series, we find that the current withstand ( $I_P$ ) of a 48 V device @ 25°C is 64 A while the requirement is 45 A at 48 V. It is interesting to note that the specified requirement of 60 A per Table 22-2 is reduced significantly by the clamping voltage subtracting from the driving voltage [7], thus proportionally reducing the surge current. This is reflected in the downward slope of the Level 3 Curve. The SMCJ48CA, (CA suffix denoting bidirectional performance for ac) or equivalent will meet the surge requirements at 25°C and 70°C but is marginal at 100°C. The next level up, the 3000 W series is recommended for 100°C performance if required (see Graph 4).

Why are the "driving" current threats ( $I_S$ ) of Levels 1 through 5 reduced with increasing voltage? Because the clamping voltage of the TVS subtracts from the open circuit driving voltage, thus lowering the driving current as illustrated in the following equation:



Is = (Voc - Vc) / Zs(Eq. 1.)= (300 V - 77.4 V) / 5 ohm= 44.5 AWhere:Is = peak driving current of surge through the TVS Voc = open circuit voltage - 300 VVc = Max clamping voltage of SMCJ48CAZs = Source impedance of driving voltage - Voc / Isc

In this equation, we see the Voc open circuit voltage of 300 V is reduced to 222.6 V, with a corresponding reduction of surge current to 44.5 A, or about 25% below the value of 60 A for the lsc specified for Level 3.

### CLAMPING VOLTAGE SIGNIFICANCE

The purpose of the TVS is to clamp the voltage spike to a level below the failure threshold of the components it is protecting. The failure threshold voltage is not the operating voltage of the protected device. All components have a margin between rated value and transient failure threshold which is usually not specified by the manufacturer.

Maximum operating voltage levels specified on data sheets for ICs and power transistors are for steady state conditions while most components can tolerate short term voltage spikes of less than 150 µs up to 50% greater values than the operating voltages. Normally the higher the voltage of the protected device, **the more narrow the margin in percentage** between maximum **operating voltage level and voltage spike failure level**. For example, a 400V rated switching transistor can usually tolerate a clamping level of 420 V or more, which is about 5% greater than its steady state operating level. In comparison, a 5 V to 15 V UART (universal asynchronous receiver transmitter) can normally withstand a 50% or greater voltage clamp above its maximum operating level. Manufacturers are reluctant to provide any other than the maximum operating voltage. The above failure threshold values are based on the writer's experience, including test measurements.

**Our third example of protection** is for a 48 V signal line monitoring status of voltage across a relay. The threat is **Waveform 4, Level 4** (750Voc/150Isc). This takes us to a higher power level device requirement that we find is the **5000 W** rated TVS shown in **Graph 5**. The peak current protection is more than twice that for our previous example, so we look for a TVS with higher power that will withstand this higher peak current surge.

Observing the  $V_{WM}$  of 48 V at Level 4 in graph 5 for 5000 W devices, we see that the maximum peak current rating for this voltage is approximately 210A @ 25°C. The derating graphs indicate that this part will operate safely at 70°C but marginal at 100°C. For 100°C performance, the higher power **PLAD6.5KP48A surface mount TVS in Graph 6** or the **PLAD7.5KP48A in graph 7 is recommended**. A unipolar device was selected because this is a dc application. Clamping of the negative transients is through the diode in the forward direction that can withstand higher surge currents than in the avalanche mode.

A fourth example of protection continues when ascending to a higher threat level protecting from a transient surge per Waveform 4, Level 5 (1600Voc/320Isc). Operating conditions are on a 28 V dc power distribution line that must withstand an abnormal voltage condition of 60 V maximum, Category B [4].

Continue working your way further into the pages noting that in **Graph 8 the 15,000 W TVS series** will withstand surge currents of **greater than 320 A at a voltage level of 60 V and 100°C.** Above 60 V, a **TVS will not conduct during the abnormal condition but will withstand a surge** > **320 A for this Waveform 4, Level 5 threat.** A good selection for this application in Graph 8 would be a **15KP64A or PLAD15KP64A.** Verify that the clamping voltage is **compatible** with the maximum **failure threshold voltage** of the protected circuit / component. This device is rated for approximately 500 A at 25°C. It has a clamping voltage of 104 V at its rated peak pulse current (Ipp) as extrapolated from the graph/data table. This device has a significant margin of about 60% at 25°C that can be derated to 100°C with a margin of safety.

The 15,000 W axial-leaded devices are often made using 3-stacked chips that have been considered the most economical method for higher power surge suppressors. The PLAD15KP series is made up of a single larger chip in a surface mount package for the same power rating as well as two stacked chips for twice the P<sub>PP</sub> rating at 30,000 W with the PLAD30KP series. With fewer internal chips stacked in series, it also allows lower voltages in these PLAD product series families where they start at 7 V and 14 V respectively. This can also be very useful for generating higher peak pulse power options as we shall observe in further examples for the severe Waveform 5A.



**Our fifth example** is one in which a 125 V dc status monitoring signal line must be protected from conditions of **Waveform 4, Level 5** (1600Voc/300Isc) in a 70°C ambient.

Continue on to **Graph 9** and locate the coordinates for the required performance. At 130V, the **PLAD30KP130A** device has a 6.4/69 µs rating of 470 A at 25°C and 380 A at 70°C; and 330A for 100°C. This selection should perform well for the application.

#### SELECTING LIGHTNING PROTECTION FOR WAVEFORM 5A

Waveform 5A is defined as having a waveform, of 40/120  $\mu$ s +/- 20%. Calculations in the following examples are based on the +20% worst case, increasing the pulse duration from 120  $\mu$ s to 144  $\mu$ s maximum. **Graphs 10 through 18 depict curves for Waveform 5A**. These protection levels are developed in the same manner as those for Waveform 4 but with lower I<sub>PP</sub> device ratings attributed to the longer Waveform 5A. The **increase in surge current / power for Waveform 5A is only 2.33** times the peak current value for a given device @10/1000  $\mu$ s found in Microsemi data sheets as stated earlier.

Referring to **Figure 4 on page 3** and the column for **Waveform 5A**, note that the voltage spike amplitudes are identical to those for **Waveform 4**. However, the Isc current is higher by a factor of 5 because of the lower source impedance of only 1 ohm compared to 5 ohms for Waveform 4. Another component of the increased threat for Waveform 5A is its 74% longer duration compared to Waveform 4.

The more severe conditions of Waveform 5A are attributed to applications involving closer proximity of lightning source including those conductors close to the skin of the aircraft, areas containing a higher density of composite materials, long power distribution lines, and long signal line runs within the airframe plus a myriad of others.

From the writer's experience, ac and dc power distribution systems may be located in areas requiring protection from Waveform 5A surges, depending on the airframe structure. With the large amounts of composite materials used in construction of newer aircraft, both power and data lines are subjected to more severe lightning threats. Most threats presented by **Waveform 5A** appear to be **Level 4** (750Voc/750Isc) based on the writers experience.

Typical Waveform 5A Level 4 threats require the higher 30 kW product ratings for protection. Multiple 30 kW devices are often wired in series or parallel to provide the surge current withstand capability for Level 4, Waveform 5A threats. Although there have been no requests, TVS devices for Level 5 threats can be designed to also meet these requirements.

**Example 1** protecting from **Waveform 5A threats** is that of a **125 V dc status signal line** subjected to **Level 2** (125Voc/125Isc). This is an easy one to solve since the operating voltage and threat are at the same level. There will be zero voltage impressed on the line because it is of the same value as the threat, hence no current is driven into the 125 V signal line and no protection is required (see EQ.1). For this same threat at lower operating voltages, protection will be required as shown in the following example.

**Example 2** protection from **Waveform 5A** is one where a low speed **32 V bidirectional signal line** is exposed to a **Level 2** (125Voc/125lsc) threat. ARINC-429 and most other signals are run through shielded wiring that provides significant lightning protection, also the line impedances are quite high, further reducing lightning threats. This issue was discussed earlier in the section on protecting from Waveform 4 threats.

For this requirement, the solution is found on Graph 13 for the 3000 W device. The closest fit is the SMLJ33CA (33V  $V_{WM}$ ) that can be derated for 100°C performance. This is a compact surface mount device in the DO-214AB with J bend tabs. The SMLJ series is a frequent choice for signal line protection from harsh lightning conditions.

**Example 3 for a Waveform 5A** threat from Level **3** (300Voc/300lsc) lightning exposure, is for a **12 V power supply**. The **3000 W device in Graph 13** will protect up to **70°C** as observed on the coordinates; however, for protection at **100°C** ambient levels, the **5000 W** device depicted in **Graph 14 is required** where the **5KP12A axial leaded** device is recommended. For surface mount, the PLAD6.5KP12A is recommended in Graph 15.

**Example 4** is more challenging protecting a **48 V off-line switching** power supply with a 100 V rated transistor and **Waveform 5A**, **threat Level 4** (750Voc/750lsc). Ambient operating temperature is 100°C and the power is



Category B with a maximum abnormal voltage surge of **60 V for 100 ms** previously described in Figure 6. Since a TVS will not withstand the power delivered by a 100 ms surge, 60 V becomes our defacto operating voltage. From **Graph 18 for the 30,000 W TVS**, our highest powered device for this voltage (PLAD30KP60A) will withstand a peak current of 727 A at 40/120  $\mu$ s, (with V<sub>c</sub> of 96.8 V) only 74 A above the threat level of 653 A at 25°C (see Eq.1). This is a close margin, but more than adequate to meet this requirement. A further level of creativity is required to meet higher temperature requirements.

One option to increase surge current capability is to use two devices of the same voltage type matched in parallel, providing twice the current capability of a single device to meet the often required 100°C ambient. They must be matched under surge conditions to ensure near equal voltage for sharing the current evenly. Two each of a 30KPA60A matched in parallel will provide the necessary protection up to 100°C with an approximate 50% safety margin. Special selected matched devices can be avoided by using two of the PLAD30KP30A in series for surface mount applications. The clamping voltage for the two devices in series is conservatively estimated to be 100 V maximum, the same value as the maximum rated operating voltage of the protected device [8]. Using two or more of the same lower voltage TVS devices in series (if available) where the voltage adds up to the desired V<sub>WM</sub> value is recommended when surge currents are beyond the capability of a single TVS of a higher selected V<sub>WM</sub> value. Multiple devices can be used as long as they are of the same type or of higher current rating when an equally divisible required number is not available.

### PROTECTING ACROSS POWER DISTRIBUTION LINES

For protection across high voltage ac power distribution lines, there is the option of stacking lower voltage, higher current rated devices in series to compensate for the inherently lower surge current ratings of high voltage TVSs. This is particularly applicable for high  $V_{WM}$  applications requiring high surge current protection across ac distribution from a **Waveform 5A Level 4 threat (750Voc/750Isc)**.

**Example 5** is for an application across a **115V ac distribution line** having an **Abnormal Voltage of 255 V** peak from 180 V rms (see Figure 5) feeding a switching power supply. A maximum clamping of 420 V is required for protection of the 400 V rated transistor within the supply. A few well chosen parts can be stacked in series which have a clamping voltage of 420 V maximum and still meet the surge current and a working voltage level equal to or slightly above the 255 V, 100 ms abnormal high voltage condition.

When reviewing the selection of available PLAD30KPxxx series devices and comparing the listed  $I_{PP}$ , remember that the current rating in the data sheet is for a 10/1000 µs waveform and Waveform 5A is 40/120 µs. Per the section on Graph Overview herein (page 5), the 10/1000 µs surge current rating is multiplied by 2.33x to obtain its higher value for the shorter 40/120 µs pulse width.

For example, we first calculate the true surge current (Is) of the Level 4 threat to the power supply using 400 V switching transistors with 420 V transient capability.

 $I_{S} = (Voc - Vc) / Zs$ (Eq. 2) = (750V - 420V) / 1 ohm = 330 A

From this simple calculation, we find the threat @  $25^{\circ}$ C is 330 A at 40/120 µs. Next we review the TVS devices available from the 30 kW ratings at 10/1000 µs such as the PLAD30KPxxx data sheet to select TVSs that provide the desired electrical parameters with surge capability of 330 A plus derating for high temperature performance.

Our target working voltage is 255 V peak, the worse case abnormal high voltage condition, or slightly higher, but still meeting conditions of maximum surge current and clamp voltage. For a trial fit on this severe requirement, we divide the working voltage by two, with a resulting value of 127.5 V which is closely rounded up to 130 V providing a PLAD30KP130CA option. Total clamping voltage of these parts in series is  $2 \times Vc$ , (Vc is 209 V) resulting in 418 V. The peak pulse current of the PLAD30KP130CA for the 40/120 µs Waveform 5A is:

 $I_{P} \text{ at } 40/120 \ \mu\text{s} = 2.33 \ \text{x} \ I_{PP} \text{ at } 10/1000 \ \mu\text{s} \tag{Eq. 3} \\ = 2.33 \ \text{x} \ 142 \ \text{A} \\ = 331 \ \text{Amps max} \ I_{PP}$ 

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Just a reminder that  $I_P$  is used to denote peak current rating at a waveform other than 10/1000 µs while  $I_{PP}$  is the 10/1000 µs data sheet rated peak pulse current. This limit of 331 A for the TVS is approximately equal to that calculated for this surge event of 330 A in Eq. 2, and is only suitable for 25°C ambient temperatures, with no margin for derating to higher temperatures. When using multiple TVS devices in series resulting in higher V<sub>C</sub> values, the calculations in Eq. 2 indicate the red threat level curves decline in value or effectively shift to the left with respect to the individual V<sub>WM</sub> voltages for each TVS device used in series. This also results in improved margin of the green, blue and yellow performance curves relative to the I<sub>S</sub> calculations for threat level curves where the 18 graphs only show I<sub>S</sub> relations for individual TVS devices.

Three devices in series will provide a greater surge protection level. Dividing 255 V by three provides a PLAD30KP85CA for a surface mount package option with a clamp voltage of 137 V each. Total clamp voltage for the three parts in series is the additive values or 137 V x 3 yielding 411 Volts on the PLAD example where  $V_c$  is still conservative for the 420 V minimum requirement.

The peak surge current ( $I_P$ ) rating for these three devices rated for a 4/120 µs, Waveform 5A is derived in the same manner as in the previous example yielding 508 A for  $I_P$  that provides a 54% increased margin from 330 A in Eq 2 and can also be conservatively derated to 100°C. In this example, the stacked devices were all the same voltage without fractional values remaining. If this is not the case, use a lower voltage device which matches closest when added together but is still above the system operating voltage.

**Example 6** is for protection across **230 V ac lines** requires performance at an abnormal voltage surges up to 360 V rms or 509 V peak for 100 ms that is twice the value in figure 5, shown on page 4. TVS protection voltage levels are double the values previously illustrated for 115V. The same techniques are used for selecting lightning protection devices. In some applications where narrow margins exist between operating voltage and clamping voltage, the designer is encouraged to consult the factory for assistance.

**Example 7:** For protection across **28 V, Category B dc bus lines, threat Level 4 of Waveform 5A**, the net surge current is higher resulting from the lower clamp voltage as shown with a PLAD30KP60A selected for protection. This 66.7 V minimum breakdown device will adequately meet the 60 V for 100 ms, "Abnormal Voltage" condition.

I<sub>S</sub> = (Voc - Vc) / Zs = (750V - 96.8V) / 1 ohm = 653 A

(Eq. 4)

The Level 4 surge current threat for a 28 V dc line is almost double that for the 115 V ac requirement previously shown since the clamping voltage of 96.8 V is far less across the ac power line in equation 4 above. The  $I_P$  of the PLAD30KP60A for a 40/120 µs pulse is 312 x 2.33 = 727 Amps providing a margin of 11% above the  $I_P$  requirement of 653 A for a 25°C ambient.

Many applications require the lowest clamping voltage that can be attained. Since the abnormal surge voltage does not exceed 60 V, using a device with a breakdown voltage equal to this value has been acceptable for most applications. Lower voltage TVSs providing lower clamping voltage than the PLAD30KP60A described above include the PLAD30KP58A and PLAD30KP54A. Minimum breakdown voltages at 25°C are 64.4 V and 60.0 V respectively on the PLAD products with minimum clamping voltages of 93.6 V and 87.1 V respectively. Maximum I<sub>P</sub> for the PLAD30KP54A is 797 A at 40/120  $\mu$ s or 2.33 x 342. Let's also compare this to the Waveform 5 Level 4 threat limit calculation.

I<sub>S</sub> =(Voc - Vc) / Zs = (750V - 87.1V) / 1 ohm = 662.9 A

(Eq. 5)

Compared to the PLAD30KP60A, the PLAD30KP54A offers 9.9 Amps of additional current protection and a lower clamping voltage by 9.7 V for protecting more sensitive components. Although the lower end of the breakdown voltage ( $V_{BR}$ ), is identical to the maximum Abnormal Voltage (60.0 V), the TVS will draw current when the temperature drops below 25°C for example, since TVS devices have a positive temperature coefficient of voltage. However the current drawn by the TVS will be minimal and only sufficient to maintain a breakdown voltage equal to the maximum Abnormal Voltage during this brief time period of 100 ms. For a power line, this small amount of extra current drawn for heating the TVS should present no problem.



When comparing this analysis of a 54 Volt  $V_{WM}$  in **Graph 18** for Level 4 protection, it is apparent this is sufficient for 25°C but not for 70°C or above. For higher ambient temperatures as in earlier examples, the easiest practice is to place two devices in series of one-half the voltage of the PLAD30KP54A. This is available in the surface mount series with the PLAD30KP28A to almost double the surge current or three devices with the PLAD30KP18A to triple the surge current capabilities. In those TVS series where these lower voltage selections have not been previously available (such as in the older 30KPxxx axial-leaded series), the alternative for increasing surge current capability is with matched parallel devices. Voltage matching is performed under surge conditions to ensure a very close match, typically within the range of +/- 0.5%, for even load sharing between devices. This is normally performed by the manufacturer. Parallel matched TVSs for aircraft lightning protection and general heavy duty surge protection have been in use for several decades and have a record of proven performance. This method has also been thoroughly tested in battle performance in military ships and aircraft.

For higher current applications using single components beyond the limitations of Microsemi's 30,000 watt devices, there is the RT130KP275CV thru 295CV or CA series, which is rated at 40,000 W for 10/1000  $\mu$ s. They are characterized for Waveform 4, 6.4/69  $\mu$ s and available in voltages intended for protection across 115 ac lines including abnormal high voltage conditions. Using the conversion equations reviewed in MicroNote No. 127, they may be applicable for other protection requirements confronted by the designer.

Copies of the RT130KP275CV thru 295CV or CA series data sheets can be downloaded from our web site at <u>www.microsemi.com</u>.

#### MULTIPLE SURGE EVENTS

Further inquiries have been made for devices to withstand multiple surge events as also defined by RTCA/DO-160. The profile of the surge consists of a maximum value followed by multiple strokes. Since there is cumulative heating effects from these multiple surges, the lower thermal resistance junction to case (bottom) of the PLAD designs make them a better choice. Also reference MicroNote 133 on our web site [9].

#### SUMMARY / CONCLUSIONS

This document is the fifth in our series of MicroNotes providing selection guidance specifically for the avionics design engineer (the others include MicroNotes Nos. 126. 127, 130, and 133). It translates the data sheet peak pulse current ratings of the 10/1000  $\mu$ s waveform into the surge rating equivalents to meet the Waveform 3, 4 and Waveform 5A threats described in RTCA/DO-160.

A matrix of graphs for each device family from 500 W peak pulse power up through 30,000 W has been derived for surge ratings of each device family at 25°C, 70°C, and 100°C for the above threats. Each graph is supported with a table listing the data sheet electrical parameters for the individual components listed along with calculated data points for the curves.

Using the examples and guidelines in the text, the designer is able to select directly from the graph of a device to fit his requirement with minimal calculating and guesswork. We expect those using this document to save valuable design time by more rapidly selecting a TVS correctly rated for a given application.

This is our second issue at presenting this information in graph selection format. We expect other revisions to keep up with the emerging technologies and updates of the RTCA/DO-160 specification and its latest revision. We also still recognize there is room for modifications to make this document more user friendly. To help achieve this goal, constructive comments from the user are welcome. It is Microsemi's desire to provide the design engineer with the most up to date design information to assist in achieving his/her goal more efficiently.



#### For additional technical information, please contact Design Support at:

#### http://www.microsemi.com/designsupport

or

#### Kent Walters (kwalters@microsemi.com) at 602-458-3212

### REFERENCES

- [1] Clark, O. M., MicroNote<sup>™</sup> No. 127, Microsemi Corp., pg. 6
- [2] Clark, O. M., MicroNote No. 127, Microsemi Corp., pg. 6
- [3] Walters, K., MicroNote No. 130, Microsemi Corp.,
- [4] RTCA/DO-160E, Section 16, Figure 16-5, pgs. 16-37
- [5] RTCA/DO-160E, Section 16, Figure 16-6, pgs. 16-38
- [6] Clark, O. M., MicroNote No. 127, Microsemi Corp., pg. 10
- [7] Clark, O. M., MicroNote No. 127, Microsemi Corp., pg. 17
- [8] Clark, O. M. and Walters, K. MicroNote No. 112, Microsemi Corp.
- [9] Walters, K., MicroNote No. 133, Microsemi Corp.



# *Index to* DIRECTselect Graphs and Datapoints

Graph #	Waveform Rating	Power*	Pg #
Graph 1	Waveform 4	500 W	14
Graph 2	Waveform 4	600 W	15
Graph 3	Waveform 4	1500 W	16
Graph 4	Waveform 4	3000 W	17
Graph 5	Waveform 4	5000 W	18
Graph 6	Waveform 4	6500 W	19
Graph 7	Waveform 4	7500 W	20
Graph 8	Waveform 4	15,000W	21
Graph 9	Waveform 4	30,000W	22
Graph 10	Waveform 5A	500W	23
Graph 11	Waveform 5A	600W	24
Graph 12	Waveform 5A	1500W	25
Graph 13	Waveform 5A	3000W	26
Graph 14	Waveform 5A	5000W	27
Graph 15	Waveform 5A	6500W	28
Graph 16	Waveform 5A	7500W	29
Graph 17	Waveform 5A	15,000W	30
Graph 18	Waveform 5A	30,000W	31

\* Power rating at 10/1000 µs

Rev 1: 11/2013

Microsemi.

Graph 1: RTCA/DO-160, Waveform 4, Levels 1 through 4, 500 W TVS Series



#### Data Points for Curves in Graph 1

Waveform 4 RTCA/DO-160 using 500 W TVS Diodes

500	W TVS @1	10/1000 µs	Conversio	n to 6.4/69		nreat for Lev	its for the l rels shown c Levels 1-4		Microsemi TVs Part Numbers compliant to RTCA/DO-160	
v <sub>wm</sub> v	V <sub>c</sub> V	I <sub>PP</sub> 500 W 10/1000 μs A	I <sub>P</sub> 25 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 100 <sup>0</sup> C 6.4/69 μs Α	1 50V/10A A	2 125V/25A A	3 300V/60A A	4 750V/150A A	Standard Capacitance • Axial Lead
5 6 7	9.2 10.3 12.0	54.3 48.5 41.7	179 160 138	146 131 113	125 112 96.6	8.2 7.9 7.6	23.1 22.9 22.6	58.2 57.9 57.6	148.2 147.9 د	P5KE5.0A-170A, CA 1N6103A-6137A 1N6461-6468
8 9 10	13.6 15.4 17.0	36.7 32.5 29.4	121 107 97	99 88 79.5	84.7 74.9 67.9	7.2 7.0 6.6	22.8 21.9 21.6	57.2 56.9 56.6	Over limit 25 °C	Low Capacitance • Axial Lead SAC5.0-50
12 15 18	19.9 24.4 29.2	25.1 20.6 17.2	83 68 57	68.0 55.8 46.7	58.1 47.6 39.9	6.0 5.1 4.0	21.0 20.1 19.2	56.0 55.1 54.2	Ī	Surface Mount     SMBJSAC5.0-50
20 28 30	32.4 45.4 48.4	15.4 11.0 10.3	51 36 34	41.8 29.5 27.9	35.7 25.2 23.8	3.5 0.9	18.5 15.9 15.3	53.5 50.9 50.3		
36 40 48	58.1 64.5 77.4	8.6 7.8 6.5	29 26 22	23.7 21.3 18.0	20.3 18.2 15.4		13.4 12.1 9.5	Over limit 25 °C		Except for 1Nxxxx part numbers shown that already have military qualifications, add M prefix for source control or MA, MX, or MXL for further upgrade
50 60 70	80 96.8 113	6.0 5.2 4.4	20 17.3 14.5	16.4 14.2 11.9	14.0 12.1 10.2					screening options on plastic devices as described in Micronote 129.
80 90 100	126 146 162	4.0 3.4 3.1	13.3 11.3 10.2	10.9 9.3 8.4	9.3 7.9 7.1					



Graph 2: RTCA/DO-160, Waveform 4, Levels 1 through 4, 600 W TVS Series



#### Data Points for Curves in Graph 2

Waveform 4 RTCA/DO-160 using 600 W TVS Diodes

600	600 W TVS @10/1000 µs			Conversion to 6.4/69 µs I <sub>P</sub> Values			reat for Lev	its for the l rels shown o Levels 1-4		Microsemi TVS Part Numbers compliant to RTCA/DO-160
v <sub>wm</sub> v	V <sub>C</sub> V	I <sub>PP</sub> 600 W 10/1000 μs Α	I <sub>P</sub> 25 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 6.4/69 µs A	I <sub>P</sub> 100 <sup>0</sup> C 6.4/69 μs Α	1 50V/10A A	2 125V/25A A	3 300V/60A A	4 750V/150A A	Standard Capacitance • Axial Lead
5 6 7	9.2 10.3 12.0	65.2 58.3 50.0	217 194 166	178 159 136	152 136 116	8.2 7.9 7.6	23.1 22.9 22.6	58.2 57.9 57.6	148.2 147.9 147.6	P6KE6.8A-200A, CA • Surface Mount SMBJ5.0A-170A, CA
8 9 10	13.6 15.4 17.0	44.1 39.0 35.3	147 130 118	120 107 96.7	103 91.0 82.6	7.2 7.0 6.6	22.2 21.9 21.6	57.2 56.9 56.6	147.2 S 147.2	Add M prefix for the part numbers shown to add source control or MA, MX, or MXL for further
12 15 18	19.9 24.4 29.2	30.2 24.0 20.5	101 80.0 68.2	82.8 65.6 55.9	77.7 56.0 47.7	6.0 5.2 4.0	21.0 20.1 19.2	56.0 55.1 54.2	<ul> <li>Over limit 25 °C</li> </ul>	upgrade screening options on plastic devices as described in Micronote 129.
20 28 30	32.4 45.4 48.4	18.5 13.2 12.4	61.3 43.9 41.3	50.2 35.9 33.9	42.9 30.7 28.9	3.5 0.9 0.3	18.5 15.9 15.3	53.5 50.9 <b>2</b>		
36 40 48	58.1 64.5 77.4	10.3 9.3 7.7	34.3 31.0 25.6	28.1 25.4 20.9	24.0 21.7 17.9	0	13.4 12.1 9.5	Over limit 25 °C		
50 60 70	80.0 96.8 113	7.1 5.6 5.3	23.6 20.6 17.6	19.3 16.9 14.4	16.5 14.4 12.3		9.0 5.6 2.4			
80 90 100	126 146 162	4.7 4.1 3.7	15.6 13.6 12.3	12.8 11.2 10.1	10.9 9.52 8.61	ł	V		ļ	



Graph 3: RTCA/DO-160, Waveform 4, Levels 2 through 5, 1500 W TVS Series



#### Data Points for Curves in Graph 3

Waveform 4 RTCA/DO-160 using 1500 W TVS Diodes

1500	W TVS @ <sup>.</sup>	10/1000 µs	Conversion to 6.4/69 µs Ip Values				reat for Lev	ts for the F els shown o Levels 2-5		Microsemi TVs Part Numbers compliant to RTCA/DO-160
v <sub>wm</sub> v	V <sub>c</sub> V	I <sub>PP</sub> 1500 W 10/1000 μs A	I <sub>P</sub> 25 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 100 <sup>0</sup> C 6.4/69 μs Α	2 125V/10A A	3 300V/60A A	4 750V/150A A	5 1600V/320A A	Standard Capacitance • Axial Lead
5 6 7	9.2 10.3 12.0	163 146 125	543 486 416	445 398 341	380 340 291	23.1 22.9 22.6	58.2 57.9 57.6	148.2 147.9 147.6	318.2 317.9 317.6	1.5KE6.8A-400A, CA 1N5629A-1N5665A 1N5907, 1N5908 1N6036A-1N6072A
8 9 10	13.6 15.4 17.0	110 97.4 88.2	366 324 294	300 266 241	256 227 206	22.8 21.9 21.6	57.2 56.9 56.6	147.2 146.9 146.6	317.3 316.9 316.6	1N6138A-1N6073A 1N6469-1N6476 1N8110-1N8146
12 15 18	19.9 24.4 29.2	75.3 61.5 51.4	251 205 171	206 168 140	176 144 120	21.0 20.1 19.2	56.0 55.1 54.2	146.0 145.1 144.2	0.616 2 11 52	• Surface Mount SMCJ5.0A-170A, CA Low Capacitance
20 28 30	32.4 45.4 48.4	46.3 33.0 31.0	154 110 103	126 90.2 84.5	108 77.0 72.1	18.5 15.9 15.3	53.5 50.9 50.3	143.5 140.9 وي	<ul> <li>Over limit 25</li> </ul>	• Axial Lead LC6.5-170A LC66.5-170A
33 40 48	53.3 64.5 77.4	28.1 23.2 19.4	93.6 77.2 64.6	76.7 63.3 52.0	65.5 54.0 45.2	14.3 12.1 9.5	49.3 47.1 44.5	Over limit 25 °C		• Surface Mount SMCJLCE6.5-170A
50 60 70	80.0 96.8 113	18.2 15.5 13.3	60.6 51.6 44.2	49.6 42.3 36.2	42.4 36.1 30.9	9.0 5.6 2.4	44.0 40.6 37.4	Ī		Except for 1Nxxxx part numbers shown that already have military qualifications, add M prefix for source control or
80 90 100	126 146 162	11.4 10.3 9.3	38.0 34.7 31.0	31.2 28.1 25.4	26.6 24.0 21.7	o ♥	34.8 30.8 27.6	ļ	ļ	MA, MX, or MXL for further upgrade screening options on plastic devices as described in Micronote 129.







#### Data Points for Curves in Graph 4

Waveform 4 RTCA/DO-160 using 3000 W TVS Diodes

3000	3000 W TVS @10/1000 μs		Conversion to 6.4/69 µs I <sub>P</sub> Values			Peak Surge Currents for the Red Curves* I <sub>s</sub> Threat for Levels shown on graph Threat Levels 2-5				Microsemi TVS Part Numbers compliant to RTCA/DO-160
V <sub>WM</sub> V	v <sub>c</sub> v	I <sub>PP</sub> 3000 W 10/1000 μs A	I <sub>P</sub> 25 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 100 <sup>0</sup> C 6.4/69 μs Α	2 125V/10A A	3 300V/60A A	4 750V/150A A	5 1600V/320A A	Standard Capacitance • Surface Mount
5 6 7	9.2 10.3 12.0	326 291 250	1085 969 832	889 794 682	759 678 582	23.2 22.9 22.6	58.1 57.9 57.6	148.2 147.9 147.6	318.1 317.9 317.6	SMLJ5.0A-170A, CA Add M prefix for the part numbers shown to add source control or
8 9 10	13.6 15.4 17.0	221 195 176	736 649 586	603 532 480	515 454 410	22.8 21.9 21.6	57.2 56.9 56.6	147.2 146.9 146.6	317.3 317.0 316.6	MA, MX, or MXL for further upgrade screening options on plastic devices as described in
12 15 18	19.9 24.4 29.2	151 123 103	502 409 343	412 335 281	351 286 240	21.0 20.1 19.2	56.0 55.1 54.2	146.0 145.1 144.1	316.0 315.1 314.1	Micronote 129.
20 28 30	32.4 45.4 48.4	92.6 66.0 62.0	308 220 206	252 180 169	215 154 144	18.5 15.9 15.3	53.5 50.3 50.3	143.5 140.9 140.3	313.5 310.9 310.3	
33 40 48	53.3 64.5 77.4	56.2 46.4 38.8	187 154 129	153 126 105	130 107 90.3	14.3 12.1 9.5	49.3 47.1 44.5	139.3 137.1 138.5	Over limit 25 °C	
50 60 70	82.4 96.8 113	36.4 31.0 26.6	120 103 88.6	98.4 84.5 72.6	84.0 72.1 62.0	8.5 5.6 2.4	43.5 40.6 37.4	134.2 ్లు కి	-Over II	
80 90 100	126 146 162	22.8 20.6 18.6	75.9 68.6 61.9	62.2 56.2 50.7	53.1 48.0 43.3	o ♥	34.8 30.8 27.6	Over limit 25	Ļ	



Graph 5: RTCA/DO-160, Waveform 4, Levels 3 through 5, 5000 W TVS Series



Data Points for Cu	rves in	Graph 5	5

Waveform 4 RTCA/DO-160 using 5000 W TVS Diodes

5000 W TVS @10/1000 µs			Conversio	on to 6.4/69	µs I <sub>P</sub> Values	Peak Surge Currents for the Red Curves* I <sub>s</sub> Threat for Levels shown on graph Threat Levels 3-5			Microsemi TVS Part Numbers compliant to RTCA/DO-160
v <sub>wm</sub> v	v <sub>c</sub> v	I <sub>PP</sub> 5000 W 10/1000 μs Α	I <sub>P</sub> 25 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 6.4/69 µs A	I <sub>P</sub> 100 <sup>0</sup> C 6.4/69 μs Α	3 300V/60A A	4 750V/150A A	5 1600V/320A A	Standard Capacitance • Axial Lead
5 6 7	9.2 10.3 12.0	543 485 417	1808 1615 1389	1482 1316 1138	1266 1124 972	58.2 57.9 57.6	148.2 147.9 147.6	318.2 317.9 317.6	5KP5.0A - 110, CA Add M prefix for the part numbers
8 9 10	13.6 15.4 17.0	367 325 294	1222 1082 979	1002 889 803	855 757 685	57.2 56.9 56.6	147.2 146.9 146.6	317.3 317.0 316.6	shown to add source control or MA, MX, or MXL for further upgrade screening options on plastic devices as described in
12 15 18	19.9 24.4 29.2	251 206 172	835 686 572	684 562 469	584 480 400	56.0 55.1 54.2	146.0 145.1 144.2	316.0 315.1 314.0	Micronote 129.
20 28 30	32.4 45.4 48.4	154 110 103	512 366 342	420 300 280	358 256 239	53.5 50.9 50.3	143.5 140.9 140.3	313.5 310.9 310.3	
36 40 50	58.1 64.5 80.0	86 78 60	286 260 200	234 213 164	200 182 140	48.3 47.1 44.0	138.4 137.1 134	308.3 307.1 304.0	
60 70 80	96.8 113 126	52 44 40	173 146 133	142 119 109	121 102 93.1	40.6 37.4 34.8	131 127 124	Over limit 25 °C	
90 100 110	146 162 177	113 31 28	34 103 93.2	92.7 84.5 76.4	79.1 72.1 65.2	30.8 27.6 24.6	121 118 115	<b>●</b> 0ve	





# Graph 6: RTCA/DO-160, Waveform 4, Levels 3 through 5, 6500 W TVS Series

# Data Points for Curves in Graph 6

Waveform 4 RTCA/DO-160 using 6500 W TVS Diodes

6500	6500 W TVS @10/1000 µs			on to 6.4/69	µs I <sub>P</sub> Values	Peak Surge Currents for the Red Curves* I <sub>s</sub> Threat for Levels shown on graph Threat Levels 3-5			Microsemi TVS Part Numbers compliant to RTCA/D0-160
v <sub>wm</sub> v	V <sub>c</sub> V	I <sub>PP</sub> 6500 W 10/1000 μs A	I <sub>P</sub> 25 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 6.4/69 µs A	I <sub>P</sub> 100 <sup>0</sup> C 6.4/69 μs Α	3 300V/60A A	4 750V/150A A	5 1600V/320A A	Standard Capacitance <ul> <li>Surface Mount</li> </ul>
10	17.0	383	1275	1045	892	56.6	146.6	316.6	PLAD6.5KP10A – 48A, CA
11	18.2	358	1192	977	834	56.4	146.4	316.4	
12	19.9	327	1089	893	762	56.0	146.0	316.0	
13	21.5	302	1006	825	704	55.7	145.7	315.7	
14	23.2	280	932	764	652	55.4	145.4	315.4	
15	24.4	267	889	729	622	55.1	145.1	315.1	
16	26.0	250	833	683	583	54.8	144.8	314.8	
17	27.6	236	786	645	550	54.5	144.5	314.5	
18	29.2	223	743	609	520	54.2	144.2	314.0	
20	32.4	202	673	552	471	53.5	143.5	313.5	
22	35.5	183	609	499	426	52.9	142.9	312.9	
24	38.9	167	556	456	389	52.2	142.2	312.2	
26	42.1	154	513	421	359	51.6	141.6	311.6	
28	45.5	143	476	390	333	50.9	140.9	310.9	
30	48.4	135	450	369	315	50.3	140.3	310.3	
33	53.3	123	410	336	287	49.3	139.3	309.3	
36	58.1	111	370	303	259	48.3	138.4	308.3	
40	64.5	101	336	276	235	47.1	137.1	307.1	
43	69.4	93	310	254	217	46.1	136.1	306.1	
45	72.7	89	296	243	207	45.5	135.5	Over Limit	
48	77.4	85	283	232	198	44.5	134.5	25°C	





# Graph 7: RTCA/DO-160, Waveform 4, Levels 3 through 5, 7500 W TVS Series

## Data Points for Curves in Graph 7

Waveform 4 RTCA/DO-160 using 7500 W TVS Diodes

7500	W TVS @	910/1000 µs	Conversion to 6.4/69 $\mu s$ $I_P$ Values			Peak Surge Currents for the Red Curves* I <sub>s</sub> Threat for Levels shown on graph Threat Levels 3-5			Microsemi TVS Part Numbers compliant to RTCA/DO-160
V <sub>WM</sub> V	V <sub>c</sub> V	I <sub>PP</sub> 7500 W 10/1000 μs A	I <sub>P</sub> 25 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 100 <sup>0</sup> C 6.4/69 μs Α	3 300V/60A A	4 750V/150A A	5 1600V/320A A	Standard Capacitance • Surface Mount
10	17.0	441	1469	1205	1028	56.6	146.6	316.6	PLAD7.5KP10A – 48A, CA
11	18.2	412	1372	1125	960	56.4	146.4	316.4	
12	19.9	377	1255	1029	878	56.0	146.0	316.0	
13	21.5	349	1162	953	813	55.7	145.7	315.7	
14	23.2	323	1076	882	753	55.4	145.4	315.4	
15	24.4	307	1022	838	715	55.1	145.1	315.1	
16	26.0	288	959	786	671	54.8	144.8	314.8	
17	27.6	272	906	743	634	54.5	144.5	314.5	
18	29.2	257	856	702	599	54.2	144.2	314.0	
20	32.4	231	769	631	538	53.5	143.5	313.5	
22	35.5	211	703	576	492	52.9	142.9	312.9	
24	38.9	193	643	527	450	52.2	142.2	312.2	
26	42.1	178	593	486	415	51.6	141.6	311.6	
28	45.5	165	549	450	384	50.9	140.9	310.9	
30	48.4	155	516	423	361	50.3	140.3	310.3	
33	53.3	141	470	385	329	49.3	139.3	309.3	
36	58.1	129	430	353	301	48.3	138.4	308.3	
40	64.5	116	386	317	270	47.1	137.1	307.1	
43	69.4	108	360	295	252	46.1	136.1	306.1	
45	72.7	103	343	281	240	45.5	135.5	305.5	
48	77.4	97	323	265	226	44.5	134.5	304.5	



# Graph 8: RTCA/DO-160, Waveform 4, Levels 4 through 5, 15,000 W TVS Series



#### Data Points for Curves in Graph 8

Waveform 4 RTCA/DO-160 using 15,000 W TVS Diodes

15,000	15,000 W TVS @10/1000 μs			on to 6.4/69	µs I <sub>P</sub> Values	I <sub>s</sub> Threat for Lev	ts for the Red Curves* rels shown on graph Levels 4-5	Microsemi TVS Part Numbers compliant to RTCA/DO-160
v <sub>wm</sub> v	V <sub>c</sub> V	I <sub>PP</sub> 15,500 W 10/1000 μs A	I <sub>P</sub> 25 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 6.4/69 µs A	I <sub>P</sub> 100 <sup>0</sup> C 6.4/69 μs Α	4 750V/150A A	5 1600V/320A A	Standard Capacitance • Axial Lead
7.0	12.0	1251	4166	3416	2916	148	318	15KP22A – 280A, CA
9.0	15.4	975	3247	2663	2273	147	317	• Surface Mount
10	17.0	882	2937	2408	2056	147	317	PLAD15KP7.0A – 200A, CA
12	19.9	753	2507	2055	1755	146	316	
14	23.2	645	2148	1761	1504	145	315	
16	26.0	576	1918	1573	1343	145	315	
18	29.2	516	1718	1409	1207	144	314	Add M prefix for the part numbers shown to add source control or
22	35.5	423	1409	1155	986	143	313	
26	42.1	357	1189	975	823	142	312	
30	48.4	309	1029	844	720	140	310	MA, MX, or MXL for further upgrade
36	58.1	258	859	704	601	138	308	screening options on plastic devices
43	69.4	216	719	590	503	136	306	as described in Micronote 129.
48	77.4	195	649	532	454	135	305	
54	87.1	171	569	467	398	133	303	
60	96.8	156	519	426	363	131	301	
70	113	132	440	361	308	127	297	
90	146	102	340	279	238	121	291	
130	209	71	236	194	165	108	Over Limit 25°C	
160 200 280	259 322 452	58 47 33	193 157 110	158 129 90.0	135 110 77.0	98.2 85.6 59.6	Ļ	

**Sin Microsemi**.

Graph 9: RTCA/DO-160, Waveform 4, Levels 4 through 5, 30,000 W TVS Series



# Data Points for Curves in Graph 9

Waveform 4 RTCA/DO-160 using 30,000 W TVS Diodes

30,000	) W TVS (	@10/1000 µs	Conversio	on to 6.4/69	µs I <sub>P</sub> Values	I <sub>s</sub> Threat for Leve	s for the Red Curves* els shown on graph Levels 4-5	Microsemi TVS Part Numbers compliant to RTCA/DO-160
V <sub>WM</sub> V	v <sub>c</sub> v	I <sub>PP</sub> 30,000 W 10/1000 µs A	I <sub>P</sub> 25 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 100 <sup>0</sup> C 6.4/69 μs Α	4 750V/150A A	5 1600V/320A A	Standard Capacitance • Surface Mount
14	24.0	1251	4166	3416	2916	145.2	315.2	PLAD30KP14A – 400A, CA
16	27.2	1101	3666	3006	2566	144.6	314.6	
18	30.8	975	3247	2663	2273	143.8	313.8	
22	36.4	822	2737	2244	1916	142.7	312.7	Add M prefix for the part numbers shown to add source control or
26	43.0	696	2318	1901	1623	141.4	311.4	
30	48.8	618	2058	1688	1441	140.2	310.2	
36	58.1	516	1718	1409	1203	138.3	308.4	MA, MX, or MXL for further upgrade
43	69.4	432	1439	1180	1007	136.1	306.1	screening options on plastic devices
48	77.4	390	1299	1065	909	134.5	304.5	as described in Micronote 129.
54	87.1	342	1139	934	797	132.6	302.6	
60	96.8	312	1039	852	727	130.6	300.6	
70	113	264	879	721	615	127.4	297.4	
78	126	240	799	655	559	124.8	294.8	
90	146	204	679	557	475	120.8	290.8	
110	177	168	559	458	391	114.6	284.6	
130	209	142	473	388	331	108.2	278.2	
160	259	116	386	317	270	98.2	268.2	
180	291	104	346	284	242	91.8	261.8	
220	356	84	280	230	196	78.8	248.8	
300	483	62	206	169	144	53.4	Over Limit	
400	644	46	153	125	107	21.2	25°C	





Graph 10: RTCA/DO-160, Waveform 5A, Levels 1 through 2, 500 W TVS Series



#### Data Points for Curves in Graph 10

Waveform 5A RTCA/DO-160 using 500 W TVS Diodes

500	W TVS @'	10/1000 µs	Conversio	on to 40/120	µs I <sub>P</sub> Values	Is Threat for Le	nts for the Red Curves* vels shown on graph t Levels 1-2	Microsemi TVS Part Numbers compliant to RTCA/D0-160
v <sub>wm</sub> v	V <sub>c</sub> V	I <sub>PP</sub> 500 W 10/1000 μs A	I <sub>P</sub> 25 <sup>0</sup> C 40/120 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 40/120 µs A	I <sub>P</sub> 100 <sup>0</sup> C 40/120 μs Α	1 50V/50A A	2 125V/125A A	Standard Capacitance • Axial Lead
5 6 7	9.2 10.3 12.0	54.3 48.5 41.7	126 113 97.2	103 92.7 79.7	88.2 79.1 68.3	40.8 39.7 38.0	116 114 113	P5KE5.0A-170A, CA 1N6103A-1N6137A 1N6461-1N6468 1N8073-1N8109
8 9 10	13.6 15.4 17.0	36.7 32.5 29.4	85.5 75.7 68.5	70.1 62.1 56.1	59.8 53.0 47.9	36.4 34.6 33.0	112 110 108	Low Capacitance • Axial Lead
12 15 18	19.9 24.4 29.2	25.1 20.6 17.2	58.5 48.0 40.1	48.0 39.3 32.9	41.0 33.6 28.1	30.1 25.6 20.8	105 101 <b>양</b> 96.8 <b>왕</b>	SAC5.0-50 • Surface Mount SMBJSAC5.0-50
20 28 30	32.4 45.4 48.4	15.4 11.0 10.3	35.9 25.6 24.0	29.4 21.0 19.7	25.1 17.9 16.8	17.1 4.6 1.6	91.6 <b>1</b> 79.0 <b>1</b> 76.6	Except for 1Nxxxx part numbers shown
36 40 48	53.3 64.5 77.4	8.6 7.8 6.5	20.0 18.1 15.1	16.4 14.8 12.4	14.0 12.7 10.6		71.7 60.5 47.6	that already have military qualifications, add M prefix for source control or MA, MX, or MXL for further upgrade
50 60 70	82.4 96.8 113	6.0 5.2 4.4	14.0 12.1 10.2	11.5 9.9 8.4	9.8 8.4 7.1		42.6 28.2 12.0	screening options on plastic devices as described in Micronote 129.
80 90 100	126 146 162	4.0 3.4 3.1	9.3 7.9 7.2	7.6 6.5 5.9	6.5 5.5 5.0		Devices > 78 V <sub>WM</sub> within limits	



Graph 11: RTCA/DO-160, Waveform 5A, Levels 1 through 2, 600 W TVS Series



#### Data Points for Curves in Graph 11

Waveform 5A RTCA/DO-160 using 600 W TVS Diodes

600 W TVS @10/1000 µs			Conversio	n to 40/120	µs I <sub>P</sub> Values	Is Threat for Lev	ts for the Red Curves* els shown on graph Levels 1-2	Microsemi TVS Part Numbers compliant to RTCA/DO-160	
v <sub>wm</sub> v	V <sub>c</sub> V	I <sub>PP</sub> 600 W 10/1000 μs Α	I <sub>P</sub> 25 <sup>0</sup> C 40/120 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 40/120 µs A	I <sub>P</sub> 100 <sup>0</sup> C 40/120 μs A	1 50V/50A A	2 125V/125A A	Standard Capacitance • Axial Lead	
5 6 7	9.2 10.3 12.0	62.2 58.3 50.0	151 136 116	124 112 95.1	106 95.2 81.2	40.8 39.7 38.0	116 114 113	P6KE6.8A-200A, CA • Surface Mount SMBJ5.0A-170A, CA	
8 9 10	13.6 15.4 17.0	44.1 39.0 35.3	103 90.8 82.2	84.5 74.4 67.4	72.1 63.6 57.5	36.4 34.6 33.0	111 109 108	Add M prefix for the part numbers shown to add source control or	
12 15 18	19.9 24.4 29.2	30.2 24.0 20.5	70.4 55.9 47.8	57.7 45.8 39.2	49.3 39.1 33.4	30.1 25.6 20.8	105 101 <b>ي</b> 95.8 <b>پ</b>	MA, MX, or MXL for further upgrade screening options on plastic devices as described in Micronote 129.	
20 28 30	32.4 45.4 48.4	18.5 13.2 12.4	43.1 30.7 28.9	35.3 25.2 23.7	30.2 21.5 20.2	17.1 4.6 1.6	92.6 <b>111</b> 79.6 <b>26</b> 76.6 <b>26</b>	Micronole 129.	
36 40 48	58.1 64.5 77.4	10.3 9.3 7.7	24.0 21.7 17.9	19.7 17.8 14.7	16.8 15.2 12.5		66.9 60.5 47.6		
50 60 70	82.4 96.8 113	7.1 6.2 5.3	16.5 14.4 12.3	13.5 11.8 10.1	11.6 10.1 8.6		42.6 28.2 12.0		
80 90 100	126 146 162	4.7 4.1 3.7	10.9 9.6 8.6	8.9 7.9 7.0	7.6 6.7 6.0		Devices > 75 $V_{WM}$ within limits		





# Graph 12: RTCA/DO-160, Waveform 5A, Levels 1 through 3, 1500 W TVS Series

Data Points	for Curves	in Graph 12
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Waveform 5A RTCA/DO-160 using 1500 W TVS Diodes

1500	) W TVS @	2 <b>10/1000 µs</b>	Conversio	on to 40/120	µs I <sub>P</sub> Values		e Currents for at for Levels sh Threat Level		Microsemi TVS Part Numbers compliant to RTCA/DO-160
v <sub>wm</sub> v	V <sub>c</sub> V	I <sub>PP</sub> 1500 W 10/1000 μs A	I <sub>P</sub> 25 <sup>O</sup> C 40/120 µs A	I <sub>P</sub> 70 <sup>0</sup> C 40/120 µs A	I <sub>P</sub> 100 <sup>0</sup> C 40/120 μs Α	1 50V/50A A	2 125V/125A A	3 300/300 A	Standard Capacitance • Axial Lead
5 6 7	9.2 10.3 12.0	163 146 125	380 340 291	312 279 239	266 238 203	40.8 39.7 38.0	116 114 113	291 290 288	1.5KE6.8A-400A, CA 1N5629A-1N5665A 1N5907, 1N5908 1N6036A-1N6072A
8 9 10	13.6 15.4 17.0	110 97.4 88.2	256 227 206	210 186 169	179 159 144	36.4 34.6 33.0	111 110 108	Over limit 25 °C	1N6138A-1N6173A 1N6469-1N6476 1N8110-1N8146
12 15 18	19.9 24.4 29.2	75.3 61.5 51.4	175 143 120	144 117 98.4	122 100 84.0	30.1 25.6 20.8	105 101 95.8	Over	• Surface Mount SMCJ5.0A-170A, CA
20 28 30	32.4 45.4 48.4	46.3 33.0 31.0	108 76.9 72.2	88.6 63.0 59.2	75.6 53.8 50.5	17.1 4.6 1.6	92.6 79.6 76.6		Low capacitance • Axial Lead LC6.5-170A
36 40 48	58.1 64.5 77.4	28.1 23.2 19.4	65.5 54.0 45.2	53.7 44.3 37.1	45.8 37.8 31.6		66.9 60.5 47.6 <b>0,6</b>		LCE6.5-170A • Surface Mount SMCJLCE6.5-170A
50 60 70	82.4 96.8 113	18.2 15.5 13.3	42.4 36.1 31.0	34.8 29.6 25.4	29.7 25.2 21.7		42.6 28.2 12.0		Except for 1Nxxxx part numbers shown that already have military qualifications, add M prefix for source control or
80 90 100	126 146 162	11.4 10.3 9.3	26.6 24.0 21.7	21.8 19.7 17.8	18.6 16.8 15.2		Devices >60 V <sub>WM</sub> within limits		MA, MX, or MXL for further upgrade screening options on plastic devices as described in Micronote 129.

\* Surge currents are reduced by clamping voltage (see Eq.1). In the table above, the first three columns, V<sub>WM</sub>, V<sub>C</sub>, and I<sub>pp</sub> 1500 W are taken from the data sheet while the subsequent three columns of 40/120 µs data were derived as illustrated earlier in this document and also MicroNote™ 127. The 70 °C and 100 °C curves were added for simplifying selection since many TVS devices require derating for higher temperatures.

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Graph 13: RTCA/DO-160, Waveform 5A, Levels 1 through 3, 3000 W TVS Series



### Data Points for Curves in Graph 13

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Waveform 5A RTCA/DO-160 using 3000 W TVS Diodes

3000	W TVS @	10/1000 µs	Conversior	ı to 40/120 j	ıs I <sub>P</sub> Values	Is Threat fo	irrents for th r Levels show reat Levels 1		Microsemi TVS Part Numbers compliant to RTCA/DO-160
V <sub>WM</sub> V	V <sub>c</sub> V	I <sub>PP</sub> 3000 W 10/1000 μs Α	I <sub>P</sub> 25 <sup>0</sup> C 40/120 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 40/120 µs A	I <sub>P</sub> 100 <sup>0</sup> C 40/120 μs A	1 50V/50A A	2 125V/125A A	3 300V/300A A	Standard Capacitance • Surface Mount
5 6 7	9.2 10.3 12.0	326 291 250	759 678 582	622 556 477	531 475 408	40.8 39.7 38.0	116 114 113	290.8 289.7 288	SMLJ5.0A-170A, CA
8 9 10	13.6 15.4 17.0	221 195 176	515 454 410	422 372 336	361 318 287	36.4 34.6 33.0	111 110 108	286.4 285 283	Add M prefix for the part numbers shown to add source control or MA, MX, or MXL for further
12 15 18	19.9 24.4 29.2	151 123 103	352 287 240	289 235 197	246 201 168	30.1 25.6 20.8	105 101 95.8	280 275 <b>ي</b>	upgrade screening options on plastic devices as described in Micronote 129.
20 28 30	32.4 45.4 48.4	92.6 66.0 62.0	216 154 144	177 126 118	151 108 101	17.1 4.6 1.6	92.6 79.6 76.6	Over limit 25	
36 40 48	58.1 64.5 77.4	51.6 46.4 38.8	120 108 90.4	98.4 88.6 74.1	84.0 75.6 63.3	0	66.9 60.5 47.6	ľ	
50 60 70	82.4 96.8 113	35.9 31.0 26.6	83.6 72.2 61.9	68.5 59.2 50.7	58.5 50.5 43.3		45.0 28.2 12.0		
80 90 100	126 146 162	22.8 20.6 18.6	53.1 48.0 43.3	43.5 39.4 35.5	37.2 33.6 30.3		o ↓		



Graph 14: RTCA/DO-160, Waveform 5A, Levels 2 through 4, 5000 W TVS Series



#### Data Points for Curves in Graph 14

Waveform 5A RTCA/DO-160 using 5000 W TVS Diodes

5000	) W TVS @	₽10/1000 µs	Conversio	on to 40/120	µs Ip Values	I <sub>s</sub> Threat f		the Red Curves* own on graph s 2-4	Microsemi TVS Part Numbers compliant to RTCA/DO-160
v <sub>wm</sub> v	V <sub>c</sub> V	I <sub>PP</sub> 5000 W 10/1000 μs A	I <sub>P</sub> 25 <sup>0</sup> C 40/120 μs Α	I <sub>P</sub> 70 <sup>o</sup> C 40/120 µs A	I <sub>P</sub> 100 <sup>0</sup> C 40/120 μs A	2 125V/125A A	3 300V/300A A	4 750V/750A A	Standard Capacitance • Axial Lead
5 6 7	9.2 10.3 12.0	543 485 417	1265 1130 972	1037 927 797	886 791 681	116 114 113	291 290 288	741 740 738	5KP5.0A - 110A, CA
8 9 10	13.6 15.4 17.0	367 325 294	855 757 685	701 621 562	599 530 480	111 110 108	286 285 283	736 734 లై	
12 15 18	19.9 24.4 29.2	251 206 172	585 480 401	480 394 329	410 336 281	105 101 95.8	280 275 270	Over limit 25 <sup>6</sup>	Add M prefix for the part numbers shown to add source control or MA, MX, or MXL for further
20 28 30	32.4 45.4 48.4	154 110 103	359 256 240	294 210 197	251 179 168	92.6 79.6 76.6	267 254 <b>ي</b>	Ove	upgrade screening options on plastic devices as described in Micronote 129.
36 40 48	58.1 64.5 77.4	86 78.0 65.0	200 182 151	164 149 124	140 127 106	66.9 60.5 47.6	Over limit 25		
50 60 70	82.4 96.8 113	60.0 47.0 44.0	140 109 102	115 89.4 83.6	98.0 76.3 71.4	45.0 28.2 12.0	ð 		
80 90 100	126 146 162	49.0 34.0 31.0	95.5 79.2 72.2	78.3 64.9 59.2	66.9 55.4 50.6	° ♥			

\* Surge currents are reduced by clamping voltage (see Eq.1). In the table above, the first three columns, V<sub>WM</sub>, V<sub>C</sub>, and I<sub>PP</sub> 5000 W are taken from the data sheet while the subsequent three columns of 40/120 µs data were derived as illustrated earlier in this document and also MicroNoteTM 127. The 70 °C and 100 °C curves were added for simplifying selection since many TVS devices require derating for higher temperatures.

Graph 14



Graph 15: RTCA/DO-160, Waveform 5A, Levels 2 through 4, 6500 W TVS Series



#### Data Points for Curves in Graph 15

Waveform 5A RTCA/DO-160 using 6500 W TVS Diodes

6500	W TVS @	910/1000 µs	Conversion to 40/120 µs I <sub>P</sub> Values			I <sub>s</sub> Threat	Currents for the R for Levels shown ( Threat Levels 2-4	Microsemi TVS Part Numbers compliant to RTCA/DO-160	
v <sub>wm</sub> v	V <sub>c</sub> V	I <sub>PP</sub> 6500 W 10/1000 μs Α	I <sub>P</sub> 25 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 6.4/69 µs A	I <sub>P</sub> 100 <sup>0</sup> C 6.4/69 μs Α	2 125V/125A A	3 300V/300A A	4 750V/750A A	Standard Capacitance • Surface Mount
10 11 12	17.0 18.2 19.9	383 358 327	892 834 762	731 684 625	624 584 533	108 107 105	283 282 280	733 732 730	PLAD6.5KP10A – 48A, CA
13 14 15	21.5 23.2 24.4	302 280 267	704 652 622	577 535 510	493 456 435	103 102 101	278 277 276	Over Limit 25°C	
16 17 18	26.0 27.6 29.2	250 236 223	582 550 520	477 451 426	407 385 364	99.0 97.4 95.8	274 272 271	Over L	
20 22 24	32.4 35.5 38.9	202 183 167	471 426 389	386 349 319	330 298 272	92.6 89.5 86.1	268 264 261		
26 28 30	42.1 45.5 48.4	154 143 135	359 333 315	294 273 258	251 233 220	82.9 79.5 76.6	258 254 252		
33 36 40	53.3 58.1 64.5	123 111 101	287 259 235	235 212 193	201 181 164	71.7 66.9 60.5	247 242 Over Limit		
43 45 48	69.4 72.7 77.4	93 89 85	217 207 198	178 170 162	152 145 139	55.6 52.3 47.6	25°C		



Graph 16: RTCA/DO-160, Waveform 5A, Levels 2 through 4, 7500 W TVS Series



#### Data Points for Curves in Graph 16

Waveform 5A RTCA/DO-160 using 7500 W TVS Diodes

7500	W TVS @	910/1000 µs	Conversion to 40/120 $\mu s$ $I_P$ Values			I <sub>s</sub> Threat	Currents for the F for Levels shown Threat Levels 2-4	on graph	Microsemi TVS Part Numbers compliant to RTCA/DO-160
V <sub>WM</sub> V	V <sub>c</sub> V	I <sub>PP</sub> 7500 W 10/1000 μs A	I <sub>P</sub> 25 <sup>0</sup> C 6.4/69 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 6.4/69 µs A	I <sub>P</sub> 100 <sup>0</sup> C 6.4/69 μs Α	2 125V/125A A	3 300V/300A A	4 750V/750A A	Standard Capacitance • Surface Mount
10 11 12	17.0 18.2 19.9	441 412 377	1028 960 878	843 787 720	720 672 615	108 107 105	283 282 280	733 732 730	PLAD7.5KP10A – 48A, CA
13 14 15	21.5 23.2 24.4	349 323 307	813 753 715	667 617 586	569 527 500	103 102 101	278 277 276	728 727 ي	
16 17 18	26.0 27.6 29.2	288 272 257	671 634 599	550 520 491	470 444 419	99.0 97.4 95.8	274 272 271	Over Limit 25°C	
20 22 24	32.4 35.5 38.9	231 211 193	538 492 450	441 403 369	377 344 315	92.6 89.5 86.1	268 264 261	ð	
26 28 30	42.1 45.5 48.4	178 165 155	415 384 361	340 315 296	290 269 253	82.9 79.5 76.6	258 254 252		
33 36 40	53.3 58.1 64.5	141 129 116	329 301 270	270 247 221	230 211 189	71.7 66.9 60.5	247 242 236		
43 45 48	69.4 72.7 77.4	108 103 97	252 240 226	207 197 185	176 168 158	55.6 52.3 47.6	231 227 223	ļ	

\* Surge currents are reduced by clamping voltage (see Eq 1). In the table above, the first three column (V<sub>WM</sub>, V<sub>C</sub>, and I<sub>PP</sub>) are taken from the data sheet while the subsequent three columns of 40/120 µs data were derived as illustrated earlier in this document and also MicroNoteTM 127. The 70 °C and 100 °C curves were added for simplifying selection since many TVS devices require derating for higher temperatures.

Graph 16



Graph 17: RTCA/DO-160, Waveform 5A, Levels 2 through 4, 15,000 W TVS Series



#### Data Points for Curves in Graph 17

Waveform 5A RTCA/DO-160 using 15,000 W TVS Diodes

15,0	00 W TVS µs	S @10/1000	Conversion to 40/120 $\mu s$ $I_P$ Values			I <sub>s</sub> Threat	Currents for the for Levels shown Threat Levels 3-	Microsemi TVS Part Numbers compliant to RTCA/DO-160	
V <sub>WM</sub> V	v <sub>c</sub> v	I <sub>PP</sub> 15,500 W 10/1000 μs A	I <sub>P</sub> 25 <sup>0</sup> C 40/120 μs Α	I <sub>P</sub> 70 <sup>0</sup> C 40/120 µs A	I <sub>P</sub> 100 <sup>0</sup> C 40/120 μs Α	3 300V/300A A	4 750V/750A A	5 1600V/1600A A	Standard Capacitance • Axial Lead
7.0 9.0 10	12.0 15.4 17.0	1251 975 882	2915 2272 2055	2390 1863 1685	2040 1590 1438	288 285 283	738 735 733	1588 1585 1583	15KP22A – 280A, CA • Surface Mount PLAD15KP7.0A – 200A, CA
12 14 16	19.9 23.2 26.0	753 645 576	1754 1503 1342	1438 1232 1100	1228 1052 939	280 277 274	730 727 724	1580 5°50 5°50	
18 22 26	29.2 35.5 42.1	516 423 357	1202 986 832	986 809 682	841 690 582	271 264 258	721 714 708	Over Limit 25°C	Add M prefix for the part numbers shown to add source control or
30 36 43	48.4 58.1 69.4	309 258 216	720 601 503	590 493 412	504 421 352	252 242 231	207 C 22°C		MA, MX, or MXL for further upgrade screening options on plastic devices as described in Micronote 129.
48 54 60	77.4 87.1 96.8	195 171 156	454 398 363	372 326 298	318 279 254	223 213 203	Over Limi		
70 90 130	113 146 209	132 102 71	308 238 165	253 195 135	216 167 115	187 154 91			
160 200 280	259 322 452	58 47 33	135 110 76.9	111 90.2 63.0	94.5 77.0 53.8	41 0 0			



Graph 18: RTCA/DO-160, Waveform 5A, Levels 3 through 5, 30,000 W TVS Series



# Data Points for Curves in Graph 18

Waveform 5A RTCA/DO-160 using 30,000 W TVS Diodes

30,000	D W TVS (	@10/1000 µs	Conversion to 40/120 $\mu s$ $I_P$ Values			Peak Surge Currents for the Red Curves* I <sub>s</sub> Threat for Levels shown on graph Threat Levels 3-5			Microsemi TVS Part Numbers compliant to RTCA/DO-160
V <sub>WM</sub> V	V <sub>c</sub> V	I <sub>PP</sub> 30,000 W 10/1000 μs A	I <sub>P</sub> 25 <sup>o</sup> C 40/120 µs A	I <sub>P</sub> 70 <sup>o</sup> C 40/120 µs A	I <sub>P</sub> 100 <sup>0</sup> C 40/120 μs Α	3 300V/300A A	4 750V/750A A	5 1600V/1600A A	Standard Capacitance <ul> <li>Surface Mount</li> </ul>
14 16 18	24.0 27.2 30.8	1251 1101 975	2915 2565 2272	2390 2103 1863	2040 1795 1590	276 273 269	726 723 719	1576 1573 1569	PLAD30KP14A – 400A, CA
22 26 30	36.4 43.0 48.8	822 696 618	1915 1622 1440	1570 1330 1181	1379 1135 1008	264 257 251	714 707 701	1564 1557 ب	Add M prefix for the part numbers shown to add source control or
36 43 48	58.1 69.4 77.4	516 432 390	1202 1007 909	986 826 745	841 705 636	242 231 223	692 681 673	Over Limit 25°C	MA, MX, or MXL for further upgrade screening options on plastic devices as described in Micronote 129.
54 60 70	87.1 96.8 113	342 312 264	797 727 615	654 596 504	558 509 430	213 203 187	663 653 <b>2</b>	ð 	
78 90 110	126 146 177	240 204 168	559 475 391	458 390 320	391 332 274	174 154 123	Over Limit 25°C		
130 160 180	209 259 291	142 116 104	331 270 242	271 221 198	232 189 169	91 41 9	ð 		
220 300 400	356 483 644	84 62 46	196 144 107	161 118 88	137 101 74.9	0	ļ	ļ	

\* Surge currents are reduced by clamping voltage (see Eq 1). In the table above, the first three column (V<sub>WM</sub>, V<sub>C</sub>, and I<sub>PP</sub>) are taken from the data sheet while the subsequent three columns of 40/120 µs data were derived as illustrated earlier in this document and also MicroNoteTM 127. The 70 °C and 100 °C curves were added for simplifying selection since many TVS devices require derating for higher temperatures.

Graph

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For additional technical information, please contact Design Support at: http://www.microsemi.com/designsupport or Kent Walters (kwalters@microsemi.com) at 602-458-3212

